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BFG35,115

BFG35,115 Information

For Reference Only

Part Number BFG35,115
Manufacturer NXP
Category Discrete Semiconductor Products
Transistors - Bipolar (BJT) - RF
Description TRANS NPN 10V 150MA SOT223
Package TO-261-4, TO-261AA

For the pricing/inventory/lead time, please contact us
Website: https://www.heisener.com
E-mail: salesdept@heisener.com

Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.

BFG35,115 Specifications

Manufacturer Part Number	BFG35,115
Manufacturer	NXP
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - RF
Package	TO-261-4, TO-261AA
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	18V
Frequency - Transition	4GHz
Noise Figure (dB Typ @ f)	-
Gain	-
Power - Max	1W
DC Current Gain (hFE) (Min) @ Ic, Vce	25 @ 100mA, 10V
Current - Collector (Ic) (Max)	150mA
Operating Temperature	175°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-261-4, TO-261AA
Supplier Device Package	SOT-223
	Report errors?

BFG35,115 Guarantees

Quality Guarantees
We provide 90 days warranty. *
If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

Service Guarantees
We guarantee 100% customer satisfaction.
Our experienced sales team and tech support team back our services to satisfy all our customers.

BFG35,115 Payment Methods

BFG35,115 Shipping Methods

If you have any question about BFG35,115, please do not hesitate to contact us!
Website: https://www.heisener.com
E-mail: salesdept@heisener.com